

Vishay Siliconix

Automotive Dual N-Channel 60 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	60			
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$	0.040			
$R_{DS(on)}$ (Ω) at $V_{GS} = 4.5 \text{ V}$	0.055			
I _D (A) per leg	7			
Configuration	Dual			

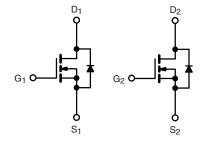
SO-8 Dual $\begin{array}{c} D_2 \\ D_2 \\ D_3 \\ D_4 \\ Top \ View \end{array}$

FEATURES

- TrenchFET® power MOSFET
- 100 % R_a and UIS tested
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



ROHS COMPLIANT HALOGEN FREE



N-Channel MOSFET N-Channel MOSFET

ORDERING INFORMATION	
Package	SO-8
Lead (Pb)-free and Halogen-free	SQ4946AEY-T1-GE3

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless		SYMBOL	LIMIT	UNIT
PARAMETER				UNIT
Drain-Source Voltage		V _{DS}	60	V
Gate-Source Voltage		V_{GS}	± 20	V
Continuous Drain Current	T _C = 25 °C	- I _D	7	
	T _C = 125 °C		4	
Continuous Source Current (Diode Conduction) a		I _S	3.6	Α
Pulsed Drain Current ^b		I _{DM}	28	
Single Pulse Avalanche Current	L = 0.1 mH	I _{AS}	18	
Single Pulse Avalanche Energy	L=0.1 IIII	E _{AS}	16.2	mJ
Maximum Power Dissipation ^b	T _C = 25 °C	Б	4	W
	T _C = 125 °C	P_{D}	1.3	VV
Operating Junction and Storage Temperature Range		T _J , T _{sta}	-55 to +175	°C

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-Ambient	PCB Mount ^c	R_{thJA}	110	°C/W	
Junction-to-Foot (Drain)		R_{thJF}	34	C/ VV	

Notes

- a. Package limited.
- b. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- c. When mounted on 1" square PCB (FR4 material).



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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static							,
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$		60	-	-	.,
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$		1.5	2.0	2.5	V
Gate-Source Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$		-	-	± 100	nA
		$V_{GS} = 0 V$	V _{DS} = 60 V	-	-	1	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V$	$V_{DS} = 60 \text{ V}, T_{J} = 125 ^{\circ}\text{C}$	-	-	50	μA
		$V_{GS} = 0 V$	$V_{DS} = 60 \text{ V}, T_{J} = 175 ^{\circ}\text{C}$	-	-	150	
On-State Drain Current ^a	I _{D(on)}	$V_{GS} = 10 \text{ V}$	$V_{DS} \ge 5 V$	20	-	-	Α
		V _{GS} = 10 V	I _D = 4.5 A	-	0.033	0.040	Ω
Drain-Source On-State Resistance a	R _{DS(on)}	V _{GS} = 10 V	I _D = 4.5 A, T _J = 125 °C	-	-	0.066	
Drain Godice on Gtate Hesistance	1 103(011)	V _{GS} = 10 V	I _D = 4.5 A, T _J = 175 °C	-	-	0.081	
		$V_{GS} = 4.5 \text{ V}$	I _D = 4 A	-	0.045	0.055	
Forward Transconductance f	9fs	V _{DS} :	$V_{DS} = 15 \text{ V}, I_D = 4.5 \text{ A}$		15	-	S
Dynamic ^b							
Input Capacitance	C _{iss}			-	600	750	
Output Capacitance	C _{oss}	$V_{GS} = 0 V$	$V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$	-	110	140	pF
Reverse Transfer Capacitance	C _{rss}	1		-	50	62	
Total Gate Charge ^c	Qg			-	11.7	18	
Gate-Source Charge ^c	Q _{gs}	V _{GS} = 10 V	$V_{DS} = 30 \text{ V}, I_D = 5.3 \text{ A}$	-	1.8	2.7	nC
Gate-Drain Charge ^c	Q_{gd}			-	2.8	4.2	
Gate Resistance	R_g		f = 1 MHz		-	6	Ω
Turn-On Delay Time ^c	t _{d(on)}		V _{DD} = 30 V, R _I = 6.8 Ω		7	11	
Rise Time ^c	t _r	V _{DD} =			3.3	5	- ns
Turn-Off Delay Time ^c	t _{d(off)}	$I_D \cong 4.4 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 1 \Omega$		-	22.4	33.5	
Fall Time ^c	t _f			-	2.1	3.2	
Source-Drain Diode Ratings and Chara	acteristics b						
Pulsed Current ^a	I _{SM}			-	-	28	Α
Forward Voltage	V _{SD}	I _F = 2 A, V _{GS} = 0 V		-	0.75	1.1	V

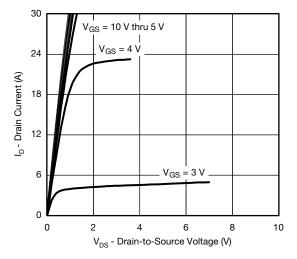
Notes

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

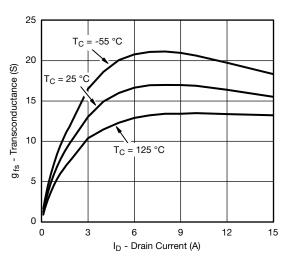
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



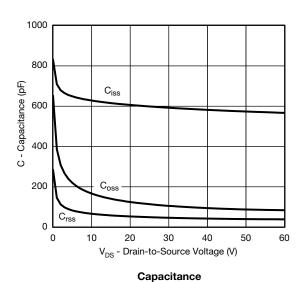
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

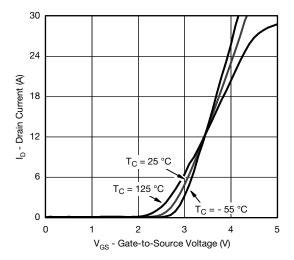


Output Characteristics

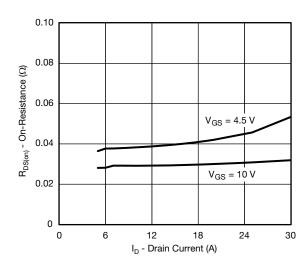


Transconductance

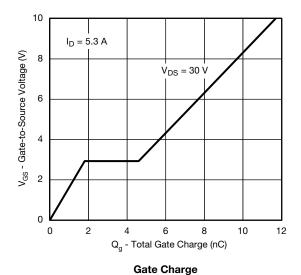




Transfer Characteristics

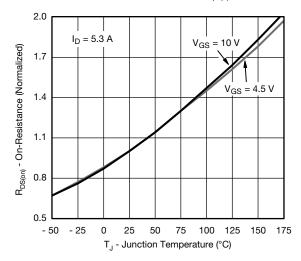


On-Resistance vs. Drain Current

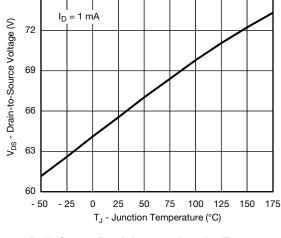




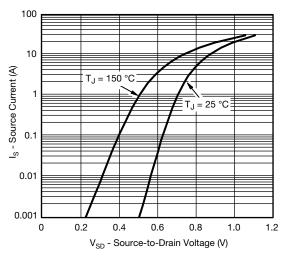
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



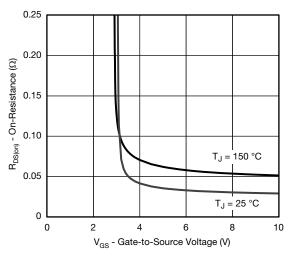
On-Resistance vs. Junction Temperature



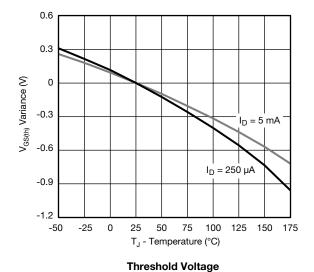
Drain Source Breakdown vs. Junction Temperature



Source Drain Diode Forward Voltage

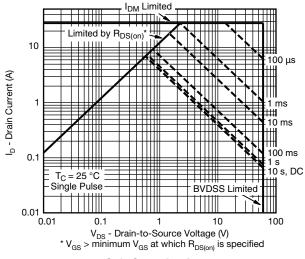


On-Resistance vs. Gate-to-Source Voltage

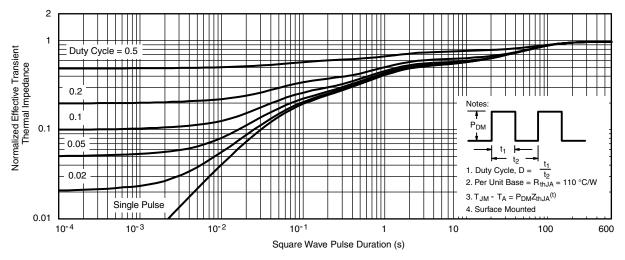




THERMAL RATINGS ($T_A = 25$ °C, unless otherwise noted)



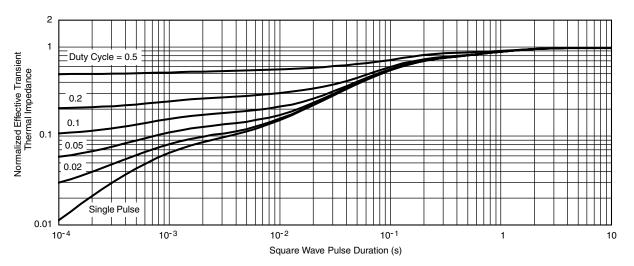
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Foot

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Foot (25 $^{\circ}\text{C})$

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg271506.



SO-8

Ordering codes for the SQ rugged series power MOSFETs in the SO-8 package:

DATASHEET PART NUMBER	OLD ORDERING CODE a	NEW ORDERING CODE	
SQ4005EY	-	SQ4005EY-T1_GE3	
SQ4050EY	SQ4050EY-T1-GE3	SQ4050EY-T1_GE3	
SQ4182EY	SQ4182EY-T1-GE3	SQ4182EY-T1_GE3	
SQ4184EY	SQ4184EY-T1-GE3	SQ4184EY-T1_GE3	
SQ4282EY	SQ4282EY-T1-GE3	SQ4282EY-T1_GE3	
SQ4284EY	SQ4284EY-T1-GE3	SQ4284EY-T1_GE3	
SQ4401EY	SQ4401EY-T1-GE3	SQ4401EY-T1_GE3	
SQ4410EY	SQ4410EY-T1-GE3	SQ4410EY-T1_GE3	
SQ4425EY	SQ4425EY-T1-GE3	SQ4425EY-T1_GE3	
SQ4431EY	SQ4431EY-T1-GE3	SQ4431EY-T1_GE3	
SQ4435EY	SQ4435EY-T1-GE3	SQ4435EY-T1_GE3	
SQ4470EY	SQ4470EY-T1-GE3	SQ4470EY-T1_GE3	
SQ4483BEEY	SQ4483BEEY-T1-GE3	SQ4483BEEY-T1_GE3	
SQ4483EY	-	SQ4483EY-T1_GE3	
SQ4532AEY	-	SQ4532AEY-T1_GE3	
SQ4840EY	SQ4840EY-T1-GE3	SQ4840EY-T1_GE3	
SQ4850EY	SQ4850EY-T1-GE3	SQ4850EY-T1_GE3	
SQ4917EY	SQ4917EY-T1-GE3	SQ4917EY-T1_GE3	
SQ4920EY	SQ4920EY-T1-GE3	SQ4920EY-T1_GE3	
SQ4937EY	SQ4937EY-T1-GE3	SQ4937EY-T1_GE3	
SQ4940AEY	SQ4940AEY-T1-GE3	SQ4940AEY-T1_GE3	
SQ4946AEY	SQ4946AEY-T1-GE3	SQ4946AEY-T1_GE3	
SQ4949EY	SQ4949EY-T1-GE3	SQ4949EY-T1_GE3	
SQ4961EY	SQ4961EY-T1-GE3	SQ4961EY-T1_GE3	
SQ9407EY	SQ9407EY-T1-GE3	SQ9407EY-T1_GE3	
SQ9945BEY	SQ9945BEY-T1-GE3	SQ9945BEY-T1_GE3	

Note

a. Old ordering code is obsolete and no longer valid for new orders



SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012







	MILLIM	IETERS	INCHES		
DIM	Min	Max	Min	Max	
Α	1.35	1.75	0.053	0.069	
A ₁	0.10	0.20	0.004	0.008	
В	0.35	0.51	0.014	0.020	
С	0.19	0.25	0.0075	0.010	
D	4.80	5.00	0.189	0.196	
Е	3.80	4.00	0.150	0.157	
е	1.27	BSC	0.050 BSC		
Н	5.80	6.20	0.228	0.244	
h	0.25	0.50	0.010	0.020	
L	0.50	0.93	0.020	0.037	
q	0°	8°	0°	8°	
S	0.44	0.64	0.018	0.026	
ECN: C-06527-Rev. I. 11-Sep-06					

DWG: 5498

Document Number: 71192 www.vishay.com 11-Sep-06



RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads Dimensions in Inches/(mm)

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<u>SQ4946AEY-T1-GE3</u> <u>SQ4946AEY-T1_GE3</u>